

5mW Visible Laser Diode

Description

The SLD1121VS is a red laser diode designed for bar code readers and measuring instruments. This features a small package and lower power consumption.

Features

- Visible light (670nm typ.)
- Small package (ϕ 5.6mm)
- Low operating current (I_{op} = 50mA typ.)
- Fundamental transverse mode

Applications

- Bar code readers
- Measuring instruments

Structure

- AlGaN_P quantum well structure laser diode
- PIN photo diode for optical power output monitor

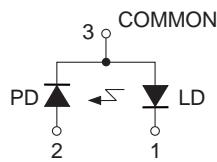
Recommended Optical Power Output

3mW

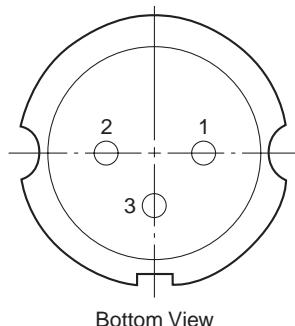
Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

- | | | | | |
|-------------------------|-----------|------------|------------------|---|
| • Optical power output | P_o | 5 | mW | |
| • Reverse voltage | V_R | LD | 2 | V |
| | | PD | 15 | V |
| • Operating temperature | T_{opr} | -10 to +50 | $^\circ\text{C}$ | |
| • Storage temperature | T_{stg} | -40 to +85 | $^\circ\text{C}$ | |

Connection Diagram



Pin Configuration



1. LD cathode
2. PD anode
3. COMMON

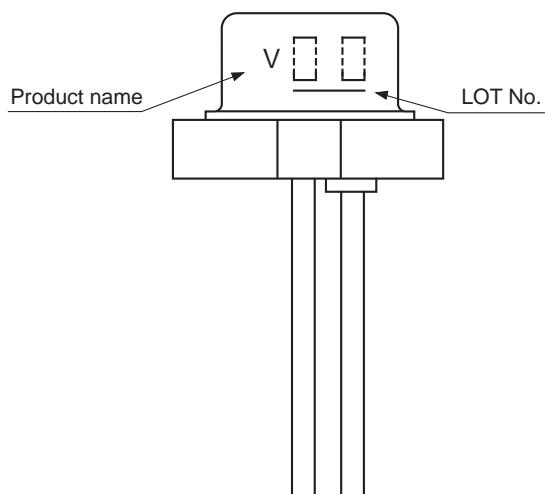
Bottom View

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Electrical and Optical Characteristics (Tc = 25°C)

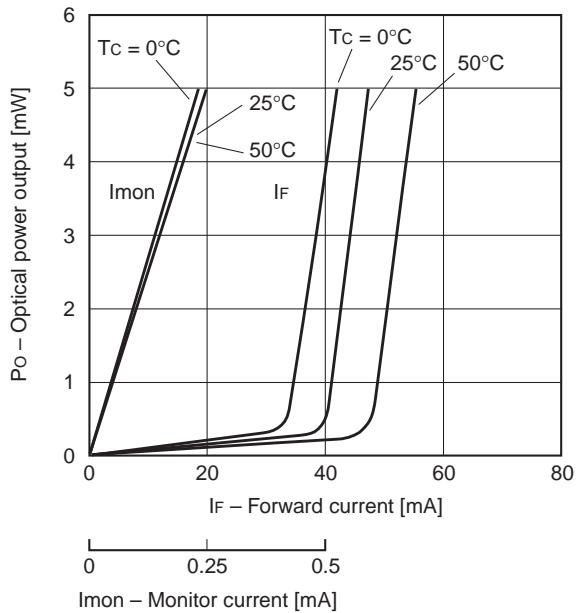
Tc: Case temperature

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit	
Threshold current	Ith			40	60	mA	
Operating current	Iop	Po = 3mW		50	70	mA	
Operating voltage	Vop	Po = 3mW		2.2	2.8	V	
Wavelength	λ	Po = 3mW	660	670	680	nm	
Radiation angle	Perpendicular θ⊥	Po = 3mW	24	32	35	degree	
	Parallel θ//		7	11	15	degree	
Positional accuracy	Position ΔX, ΔY, ΔZ	Po = 3mW			±80	μm	
	Angle Δϕ//				±3	degree	
	Δϕ⊥				±3	degree	
Differential efficiency	ηD	Po = 3mW	0.15	0.45	0.7	mW/mA	
Astigmatism	As	Z// - Z⊥		32		μm	
Monitor current	Imon	Po = 3mW, VR = 5V	0.08	0.20	0.60	mA	

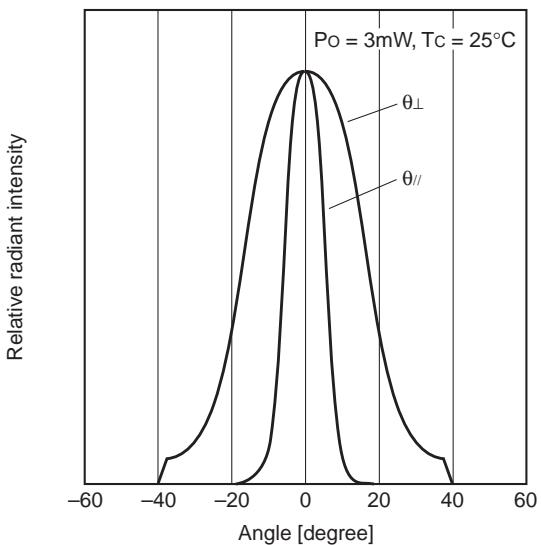
Marking

Example of Representative Characteristics

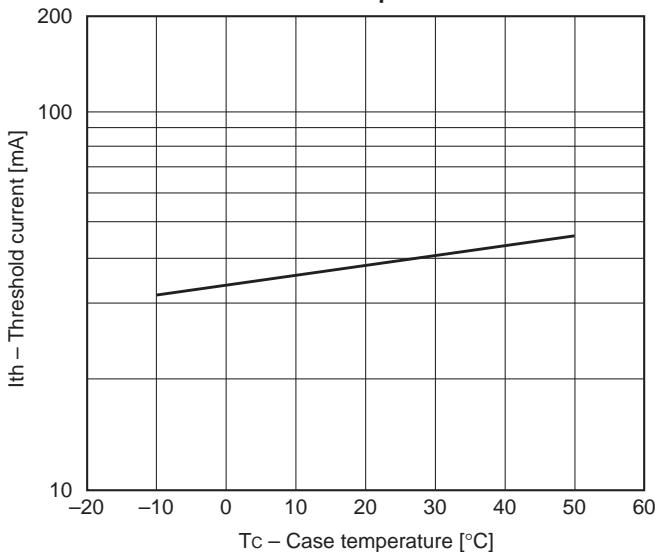
Optical power output vs. Forward current characteristics
Optical power output vs. Monitor current characteristics



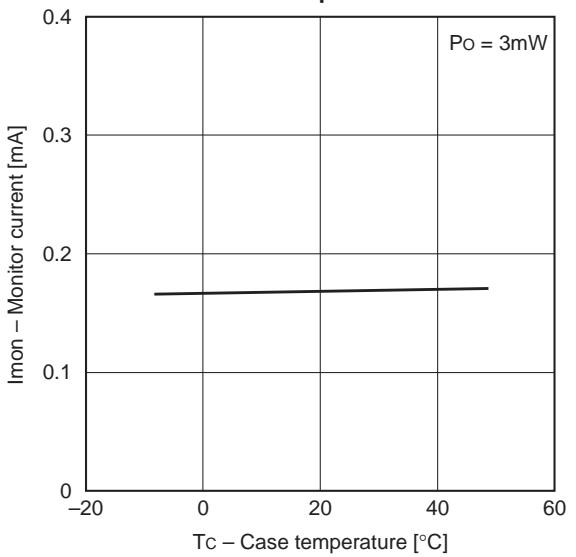
Far field pattern (FFP)

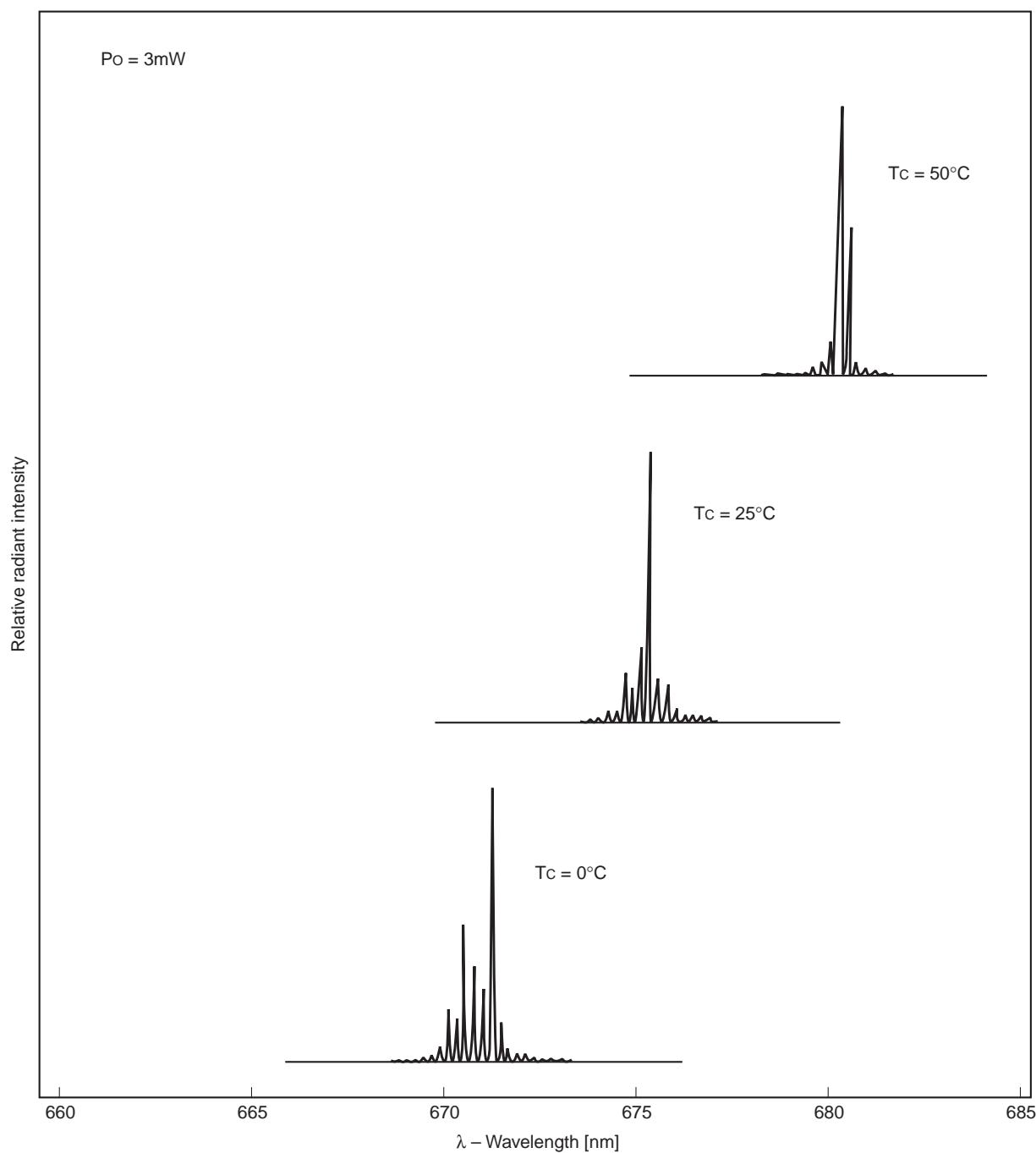


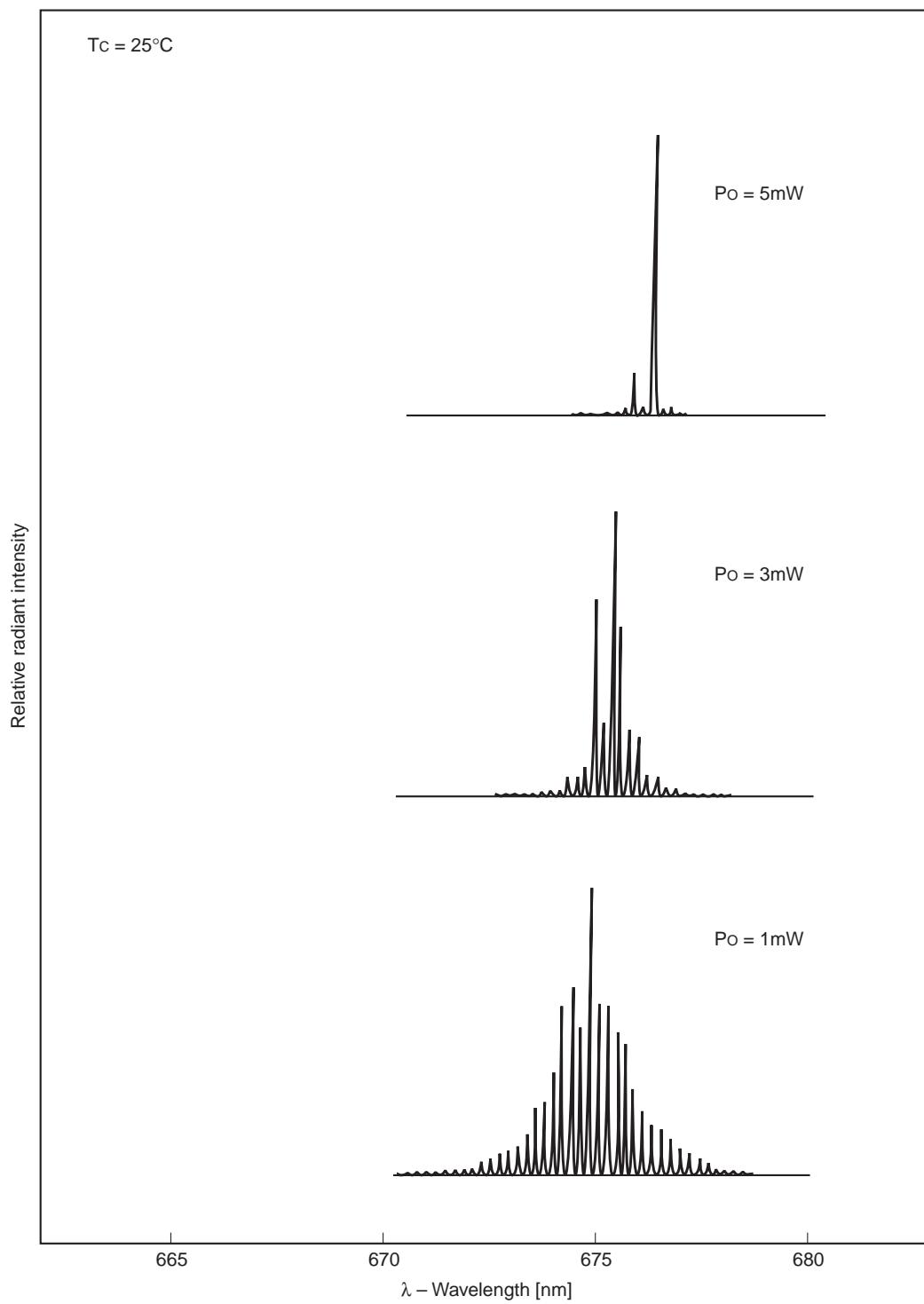
Threshold current vs. Temperature characteristics



Monitor current vs. Temperature characteristics

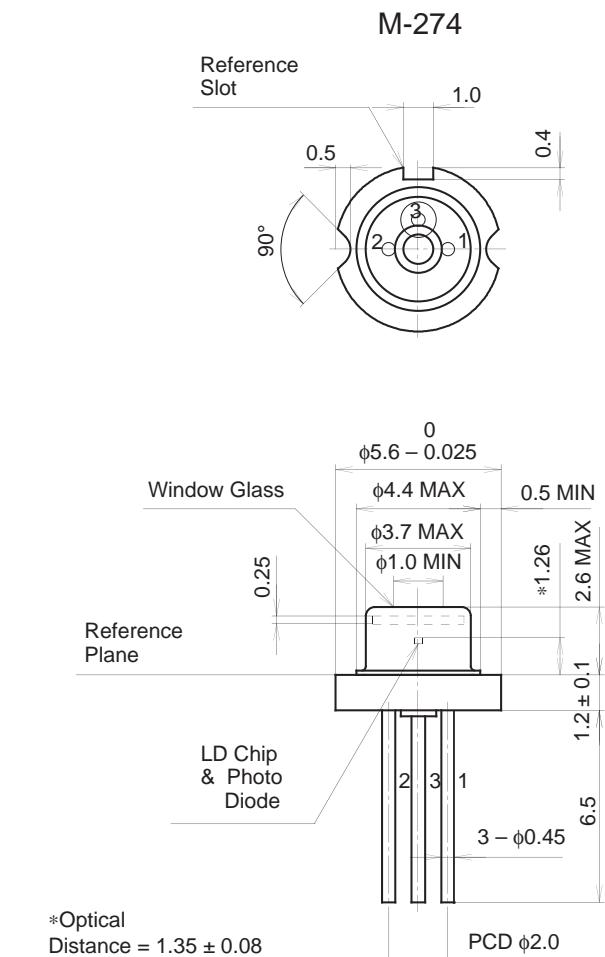


Temperature dependence of spectrum

Power dependence of spectrum

Package Outline

Unit: mm



SONY CODE	M-274
EIAJ CODE	_____
JEDEC CODE	_____

PACKAGE WEIGHT	0.3g
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